



DMT4004LPS

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	Ι <sub>D</sub> T <sub>C</sub> = +25°C
40V	2.5mΩ @ V <sub>GS</sub> = 10V	90A
	4mΩ @ V <sub>GS</sub> = 4.5V	90A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

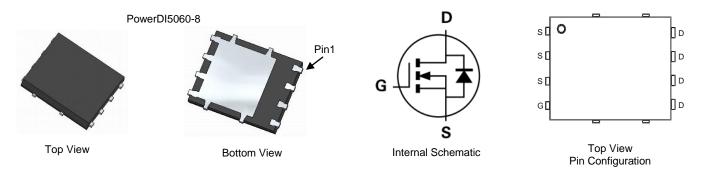
### 40V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

#### Features

- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low R<sub>DS(ON)</sub> minimizes power losses
- Low Qg minimizes switching losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight: 0.097 grams (Approximate)



## Ordering Information (Note 4)

h		
Part Number	Case	Packaging
DMT4004LPS-13	PowerDI5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

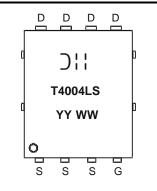
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

Notes:



) || = Manufacturer's Marking T4004LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 16 = 2016) WW = Week (01 to 53)

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# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	40	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	26 21	А
	$T_{C} = +25^{\circ}C$	I <sub>D</sub>	90	А
Continuous Drain Current (Note 6)	T <sub>C</sub> = +70°C (Note 8)		90	
Maximum Continuous Body Diode Forward Current (Note 6)	I <sub>S</sub>	70	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	100	A	
Avalanche Current, L=0.2mH		I <sub>AS</sub>	33.3	A
Avalanche Energy, L=0.2mH		E <sub>AS</sub>	110	mJ

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>0JA</sub>	47	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	138	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>θJC</sub>	0.9	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

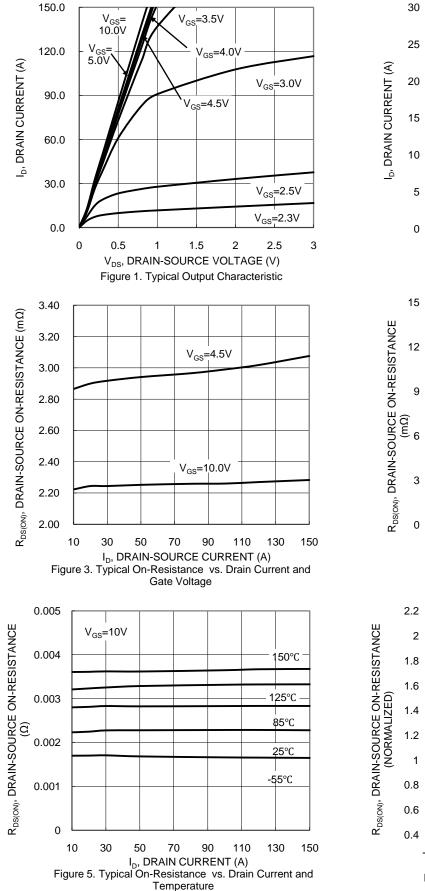
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

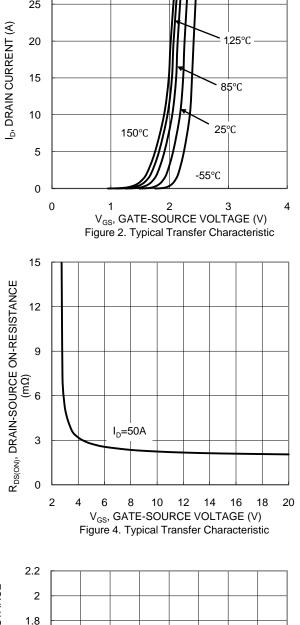
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	—	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		—	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	·						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance			—	2.5		$V_{GS} = 10V, I_D = 50A$	
	R <sub>DS(ON)</sub>		—	4	mΩ	$V_{GS} = 4.5V, I_D = 50A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 8)	·						
Input Capacitance	Ciss		4508	—		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss		1648	-	pF		
Reverse Transfer Capacitance	Crss		104	-			
Gate resistance	Rg	_	0.7	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	-	34.6	—	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	82.2	—		$V_{DD} = 20V, I_D = 30A$	
Gate-Source Charge	Q <sub>gs</sub>	_	9.9	—	nC		
Gate-Drain Charge	Q <sub>qd</sub>	_	11.2	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.9	—		V <sub>DD</sub> = 20V, V <sub>GS</sub> = 10V,	
Turn-On Rise Time	t <sub>R</sub>	_	13.3	_	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	25.9	—		$I_D = 30A, R_G = 1.6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	7.9	—			
Body Diode Reverse Recovery Time	t <sub>RR</sub>		48.4	—	ns	L 500 di/dt 1000/000	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	72.4	—	nC	— I <sub>F</sub> = 50A, di/dt = 100A/μs	

5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions Notes: b) Device mounted with exposed train pad on 25mm by 25mm 202 copper on a sill whilst operating in a steady state.
c) Thermal resistance from junction to soldering point (on the exposed drain pad).
7) Short duration pulse test used to minimize self-heating effect.
8) Guaranteed by design. Not subject to production testing.

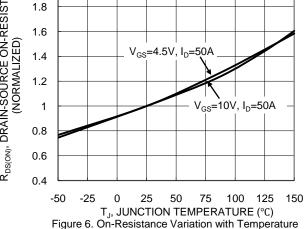


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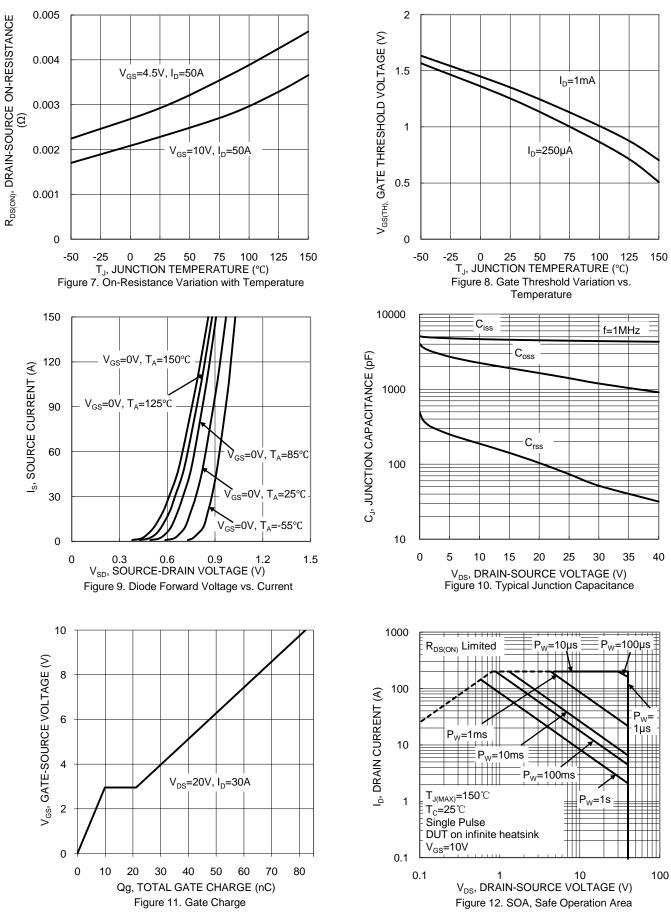
V<sub>DS</sub>= 5.0V



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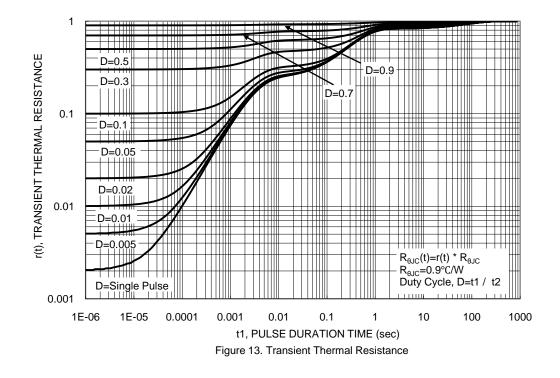
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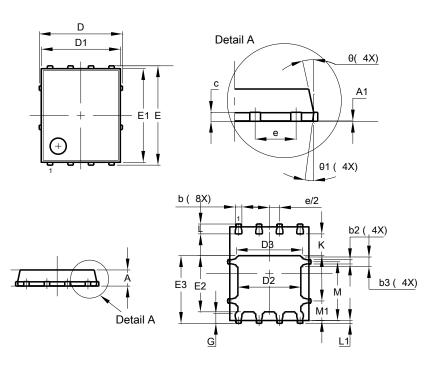
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## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

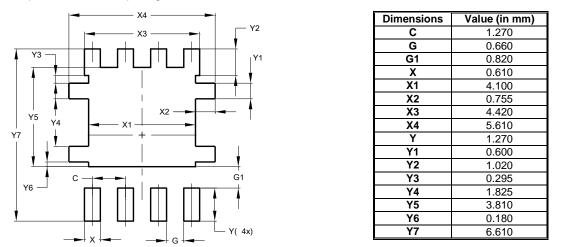


	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	5.15 BSC					
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	e	6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
e	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
Μ	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
θ	10º	12º	11º			
θ1	6°	8º	7°			
All Dimensions in mm						



### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



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